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**Alon HOFFMAN**

**LIST OF PUBLICATIONS (marked)**

**A) Ph.D. THESIS:**

1."The Influence of Alloying on O2 and NO Adsorption Processes on αCu-Al(100) Single Crystals by Means of Surface Electron Spectroscopies", Technion, Israel, 1987.

**(B)ORIGINAL PAPERS IN PROFESSIONAL JOURNALS.**

**(1)Published papers:**

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